

## **SPACE QUALIFIED LOW NOISE AMPLIFIERS**

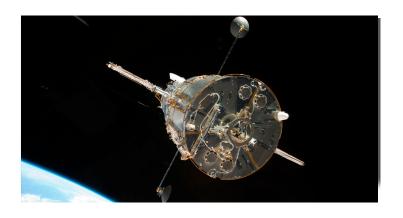
Model	Pkg	Freq	Linear Gain	Gain Fitness	Input RL	Output RL	Pout @ -1dB	NF	OIP3	Vdd	DC Current
New		(GHz)	Typ (dB)	Typ +/-(dB)	Typ (dB)	Typ (dB)	Typ (dBm)	Typ (dB)	Typ (dBm)	(V)	(mA)
MLA-01122B	C4,H6	1-10	17	1.0	14	11	16	1.6		5.0	55
MLA-0522A	87	6-18	19	2.0	10	11	20	3.0		4.5	135
LN-162315-H4	H4	1.6-2.3	26	0.3	16	16	12	1.5		5.0	38
LN-141510-H4	H4	0.150	20	1.0	12	10	16	1.0	26	12.0	30
GM-141526-H4	H4	0.150	20	1.0	14	14	26	5.0	37	12.0	150

## **SPACE QUALIFIED GAAS FETS**

Model	Pkg	Gate Width / Length	Gate Layout Method	Gate Drain Source Bond	Chip Thick- ness & VIA	S.S. Gain @12GHz Typ/Min	N.F. @12GHz Typ/Max	Ga @ N.F. @12GHz Typ/Min	P-1dB @ 12GHz Typ/Min	IP3 @ 12GHz Typ	Nominal Chip Size	Ideal Circuit
New		um		Qty	mil, y/n	dB	dB	dB	dBm	dBm	um ■ um	
MwT-1	70, 71	630/0.3	single stripe	1, 1, 2	5, no	10.0 / 9.0	2.0 / -	7.0 / -	24.0/23.0	-	775 ■ 241	FB Amp
MwT-2	70, 71	630/0.3	single stripe	2, 2, 3	5, no	8.5 / 8.0	-/-	-/-	24.5/23.0	-	775 <b>■</b> 241	BA Amp
MwT-3	70, 71	300/0.3	single stripe	1, 1, 2	5, no	11.0 / 10.0	-/-	-/-	21.0/20.0	-	406 ■ 241	BA Amp
MwT-7	70	250/0.3	single stripe	2, 2, 2	5, no	10.5 / 10.0	2.0 / -	8.0 / -	20.0/18.0	-	356 ■ 241	BA/SE Amp
MwT-LP7	70	250/0.3	single stripe	2, 2, 2	5, no	10.5 / 10.0	2.0 / -	8.0 / -	20.0/18.0	-	356 ■ 241	Oscillator
MwT-PH7	70, 71	250/0.3	single stripe	2, 1, 2	4, no	13.5 / 12.0	-	-	24.0/22.0	-	356 ■ 241	Medium Pow
MwT-8	71	2400/0.3	Interdigit	2, 2, 3	4, no	7.5 / 7.0	-	-	28.0/27.0	-	673 ■ 305	Power Amp
MwT-A9	70, 71	750/0.3	single stripe	1, 1, 2	5, no	9.0 / 8.0	-	-	25.5/23.0	-	419 ■ 292	FB Amp
MwT-PH9	70, 71	750/0.3	single stripe	1, 1, 2	4, no	10.0 / 9.0	-	-	27.0/26.0	-	419 ■ 292	Power Amp

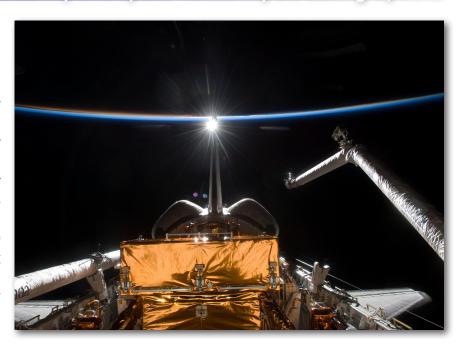
### **SPACE QUALIFIED LOW NOISE FETS**

Model	Gate Width / Length	N.F. @12GHz Typ	N.F. @4GHz Typ	Ga @ N.F. @12GHz Typ/Min	Ga @ N.F. @4GHz Typ	P-1dB @ 12GHz Typ	
		dB	dB	dB	dB	dBm	
MwT-LN240	240/0.15	0.5	0.2	10 /	13	16	
MwT-LN300	300/0.15	0.6	0.2	10 /	13	16	
MwT-LN600	600/0.15	0.5	0.2	9/8	12	20	



# HI-RELIABILITY SCREENING CAPABILITIES

MwT performs space assembly, testing, screening and qualification testing for microwave semiconductor devices, components and sub-systems. For military and space applications, the procedures are based on the MIL-PRF-38534 and other industry and government standards such as MIL-STD-202, MIL-STD-883, MIL-STD-750, MIL-STD-810, MIL-Q-9858, MIL-STD-19500 AND MIL-I-45208. We have been providing components and semiconductor devices to military and space customers successfully since 1985.



#### PRODUCTS AVAILABLE FOR SCREENING

- GaAS pHEMT, and MESFETs
- Microwave Bipolar Transistors
- Microwave Diodes
- Microwave Components, such as amplifiers Microwave Subsystems
- Microwave MMICs
- High Rel and Space Screening for other manufacturer's products. Contact factory for details.

#### **ELEMENT EVALUATION**

MwT performs element evaluation per MIL-PRF-38534 on semiconductor devices, passive elements, substrates, packages, and other elements used in microwave components and sub-systems. A typical program for GaAs FET is as follows:

Test	Method	Class H	Class K
Element Electrical			
Element Visual	2010,2072 or 2073	•	•
Internal Visual	2010,2072 or 2073		
Temperature Cycling	1010		•
Mechanical Shock or	2002		
Constant Acceleration	2001		
Burn In	1015 240 hrs.at 125°C		
Post Burn-in Electrical			
Steady State Life	1005		
Final Electrical			•
Wire-bond Evaluation	2011		
SEM	2018, 2077		•

# HYBRID ASSEMBLY FOR PACKAGED SEMICONDUCTOR DEVICES AND MICROWAVE COMPONENTS

MwT assembles active devices suches as FETs and MMIC's and passive devices, into hermetically sealed packages suitable for military and space applications. These assembly operations are controlled by MwT's stringent quality control system. Typical in-process control includes bond-pull and die-shear on sample circuits every shift. QA visual inspection on a sample basis is performed on all assembly lot.

#### HYBRID AND PACKAGED DEVICE SCREENING

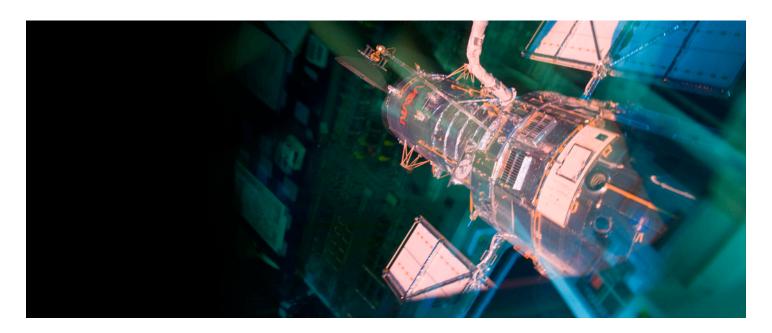
Screening is done per MIL-PRF-38534 for either class H or Class K.

Test or Inspection	Method	Condition	Class H	Class K
Non-destructive Bond-pull	2023		N/A	100%
Internal Visual	2017		100%	100%
Temperature Cycling	1010	С	100%	100%
Constant Acceleration	2001	А	100%	100%
PIND	2020	Α	N/A	100%
Pre-burn-in Electrical			100%	100%
Burn-In	1015	В	100%	100%
Final Electrical			100%	100%
Group A			100%	100%
Seal (Gross and Fine Leak)	1014	A1/C	100%	100%
Radiographic Examination	2012		N/A	100%
External Visual	2009		100%	100%

#### HYBRID AND PACKAGED DEVICE QUALIFICATIONS

Qualifications are performed according to MIL-PRF-38534 and MIL-STD-883

Test or Inspection	Method	Condition	Class H	Class K
External Visual	2009			•
PIND	2020		•	-
Temperature Cycling or	1010	C, minimum		
Thermal Shock	1011	A, minimum		
Mechanical shock and/or	2002	B, Y1 direction		
Constant Acceleration	2001	3000 g, Y1 direction		-
Seal(Gross and Fine)	1014			
Visual Inspection	1010			
End-Point Electrical				
Steady-state Life Test	1005	1000 Hr,125°C	•	
Internal Water Vapor Content	1018			
Wire-bond strength	2011			
Die Shear	2019 or 2027		•	



#### **TESTING CAPABILITIES**

#### RF Test on MMIC, Transistors and Diodes

- Small Signal Gain, P1dB, Psat, IP3, IMD3, IMD5, VSWR, Reverse Isolation, and Noise Figure 1.
- 2. S-parameter measurement
- 3. Measurements over temperature from -55°C to +85°C
- 4. Frequency Range: 100 KHz to 40 GHz

## DC Test on MMIC, Transistors and Diodes:

- 5.
- FETs:  $I_{DSS'}$  Vp,  $G_{m'}$  BV $_{GD'}$  BV $_{GS'}$   $I_{GSS}$  Bipolar Transistors:  $I_{CBO'}$   $I_{EBO}$ ,  $I_{FE'}$  BV $_{CEO'}$  BV $_{CBO'}$  BV $_{EBO}$ 6.
- 7. MMIC: IDD
- 8. Diodes: V<sub>RR</sub>, C<sub>T</sub>, Rs, Carrier Life time

#### PROGRAM MANAGEMENT

MwT has a dedicated program management team to provide support to customers for high reliability orders. From initial quoting, to the final shipment, program managers provide coordination, contact and control for all process. They provide up-to-date information on the status of the program and make sure that MwT complies with all customer requirements in hardware and software. Contact MwT for a list of space heritage. MwT provides a transparent operation to her customers.

#### **MwT QUALITY SYSTEMS:**

MwT is ISO9000-2008 registered and qualified. Our quality system complies with MIL-PRF-38534 Quality Management Program. Using statistical process control, periodic process capability certifications, design analysis, design robustness, off-line reliability assessment techniques, we insure product compliance to the quality and reliability requirements of hi-rel and space applications. We have a technology team made up of members from design engineering, production, quality control, manufacturing engineering and purchasing. The team controls the complete production line to achieve the highest process capabilities and quality. We conduct periodic assessment of the process/performances to look for opportunies for continuous improvement.

# Over 20 Years of Space and Hi-Rel Experience.



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